

# **MJ11016G**

### **MJ11016G Information**

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For Reference Only

Part Number	MJ11016G		
Manufacturer	ON Semiconductor		
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single		
Description	TRANS NPN DARL 120V 30A TO3		
Package	TO-204AA, TO-3		
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com		



Request a Quote

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



# **MJ11016G Specifications**

Manufacturer Part Number	MJ11016G	
Manufacturer	ON Semiconductor	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - Single	
Package	ТО-204АА, ТО-3	
Series	-	
Transistor Type	NPN - Darlington	
Current - Collector (Ic) (Max)	30A	
Voltage - Collector Emitter Breakdown (Max)	120V	
Vce Saturation (Max) @ Ib, Ic	4V @ 300mA, 30A	
Current - Collector Cutoff (Max)	1mA	
DC Current Gain (hFE) (Min) @ Ic, Vce	1000 @ 20A, 5V	
Power - Max	200W	
Frequency - Transition	4MHz	
Operating Temperature	-55°C ~ 200°C (TJ)	
Mounting Type	Through Hole	
Package / Case	ТО-204АА, ТО-3	
Supplier Device Package	TO-3	
	Report errors?	

#### **MJ11016G Guarantees**



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

# SERVICE GUARANTEE

#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

## **MJ11016G Payment Methods**



# MJ11016G Shipping Methods



If you have any question about MJ11016G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com